

MBRD1035CTL

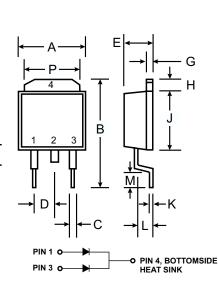
10A SURFACE MOUNT DUAL SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- Very Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, OR'ing, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: DPAK Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: See Sheet 2
- Weight: 0.4 grams (approx.)
- Ordering Information: See Below



DPAK						
Dim	Min Max					
Α	6.3	6.7				
В	_	10 0.8				
С	0.3					
D	2.3 Nominal					
E	2.1	2.5				
G	0.4	0.6				
н	1.2	1.6				
J	5.3	5.7				
к	K 0.5 Nominal					
L	1.3	1.8				
м	1.0					
Р	5.1	5.5				
All Dimensions in mm						

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	35	V
RMS Reverse Voltage	V _{R(RMS)}	25	V
Average Rectified Output Current Per Leg (See Figure 4) Per Package	Ι _Ο	5 10	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load Per Package (JEDEC Method)	I _{FSM}	75	A
Typical Thermal Resistance Junction to Case Bottom Side Per Leg (Note 1)	$R_{ ext{ heta}JC}$	2.43	°C/W
Voltage Rate of Change @ $V_R = 35V$, $T_j = 25^{\circ}C$	dv/dt	10,000	V/µs
Operating Temperature Range	Tj	-55 to +125	°C
Storage Temperature Range	T _{STG}	-55 to +125	°C

Notes: 1. Device mounted on PC board with 14mm² (.013mm thick) copper pad areas.

Ordering Information (Note 2)

Device	Packaging	Shipping
MBRD1035CTL-T	DPAK	2500/Tape & Reel

Notes: 2. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Electrical Characteristics @ T_A = 25°C unless otherwise specified

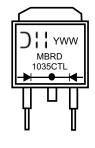
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	35	—	—	V	I _R = 500μA
Forward Voltage (Note 3)	V _{FM}			0.47 0.41 0.56 0.55	v	$\begin{array}{l} I_{F}=5A,T_{S}=~25^{\circ}C\\ I_{F}=5A,T_{S}=100^{\circ}C\\ I_{F}=10A,T_{S}=~25^{\circ}C\\ I_{F}=10A,T_{S}=~100^{\circ}C \end{array}$
Peak Reverse Current (Note 3)	I _{RM}		0.04 	2.0 30 200 5	mA mA μA mA	$\begin{array}{l} V_{R} = 35V, T_{j} = \ 25^{\circ}C \\ V_{R} = 35V, T_{j} = \ 100^{\circ}C \\ V_{R} = 17.5V, T_{j} = \ 25^{\circ}C \\ V_{R} = \ 17.5V, T_{j} = \ 100^{\circ}C \end{array}$
Typical Junction Capacitance	Cj	—	340		pF	f = 1.0MHz, V _R = 4.0V DC

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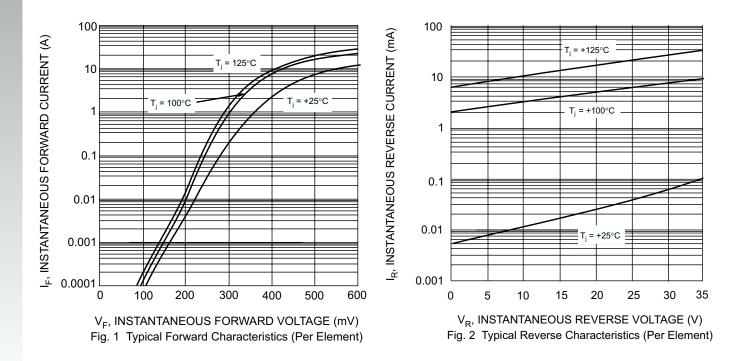
2. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

3. Short duration pulse test used to minimize self-heating effect.

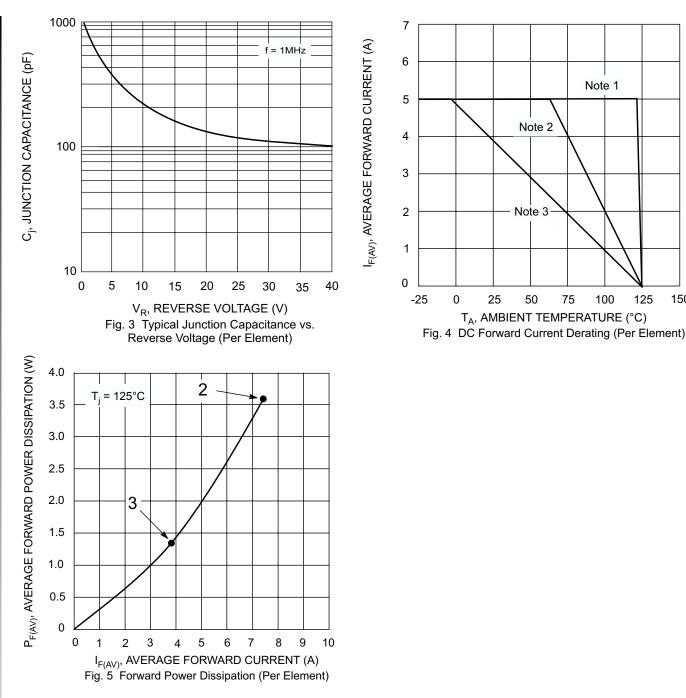
Marking Information



MBRD1035CTL = Product type marking code)|| = Manufacturers' code marking YWW = Date code marking Y = Last digit of year ex: 2 for 2002 WW = Week code 01 to 52



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1. TA = TSOLDERING POINT, $R_{\theta JC} = 2.43^{\circ}C/W$, $R_{\theta CA} = 0^{\circ}C/W$. Notes:

2. Device mounted on GETEK substrate, 2"x2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 15-30°C/W.

3. Device mounted on FR-4 substrate, 2"x2", 2 oz. copper, single-sided, pad layout as per Diodes Inc. suggested pad layout document AP02001 which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. ReJA in range of 60-75°C/W.

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